SRU6008xSx

8 A Sensitive SCR (reverse undefined)





Description:

The SRU6008xSx SCR series is specifically designed for high voltage capacitor discharge applications.

Features and Benefits:

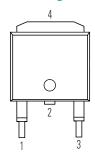
- High forward blocking voltage of 600 V
- High pulse current handling capacity
- High di/dt of 100 A/µs
- Reverse direction not desgined to function

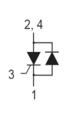
Applications:

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Typical applications are high voltage pulse generation by capacitor discharge for electric fences, CEWs (contact electric weapon) and high-power strobe lights.

Pinout Diagram





1: Cathode; 2: Anode; 3: Gate; 4: Anode

Product Summary

Characteristic	Value	Unit
I _{T(RMS)}	8	А
V_{DRM}	600	V
V_{RRM}	N/A	V
I _{GT}	0.2	mA

Absolute Maximum Ratings – Sensitive SCRs

Symbol	Characteristics	Characteristics Conditions		Units	
V _{DSM}	Non-repetitive Peak Off-state Voltage	$T_J = 25^{\circ}C$	800	V	
I _{T(RMS)}	RMS On-state Current	T 1200C	8	A	
I _{T(AV)}	Average On-state Current	T _C = 130°C	5.1		
		Single Half Cycle, f = 50 Hz, T _J (initial) = 25°C	83	А	
I _{TSM}	Peak Non-repetitive Surge Current	Single Half Cycle, f = 60 Hz, T _J (initial) = 25°C	100		
l²t	I²t Value for Fusing	$t_p = 8.3 \text{ ms}$	41	A ² s	
di/dt	Critical Rate-of-Rise of On-state Current	T _J = 150°C f = 60 Hz	100	A/µs	
I _{GM}	Peak Gate Current	$P_W = 20 \mu s$ $T_J = 150$ °C	0.5	А	
P _{G(AV)}	Average Gate Power Dissipation	T _J = 150°C	0.1	W	
T _{stg}	Storage Temperature Range	-	-40 to 150	°C	
T _J	Operating Junction Temperature Range	-	-40 to 150	°C	

Electrical Characteristics ($T_J = 25$ °C unless otherwise specified)

Symbol	Oh averatavistis	O-malisi-ma	Value			Unit
	Characteristic	Conditions	Min.	Тур.	Max.	Oilit
	Cata Trigger Current		20	_	_	
I _{GT}	Gate Trigger Current	$V_D = 12 V R_L = 60 \Omega$	_	_	200	μΑ
V _{GT}	Gate Trigger Voltage		_	_	0.8	V
dv/dt	Critical Rate of Rise of Off-stage Voltage	$V_D = V_{DRM}$; RGK = 220 Ω ; $T_J = 125$ °C	15	_	_	V/µs
$V_{\sf GD}$	Gate Non-trigger Voltage	$V_D = V_{DRM} R_L = 3.3 \text{ k}\Omega T_J = 150^{\circ}\text{C}$	0.1	_	_	V
I _H	Holding Current	I _T = 200 mA (initial)	_	_	6	mA
t _q	Turn-off Time	$I_T = 0.5 \text{ A}; t_p = 50 \mu\text{s}; \text{dv/dt} = 5 \text{V/}\mu\text{s}; \text{di/dt} = -30 \text{A/}\mu$	_	55	_	μs
t _{gt}	Turn-on Time	$I_{G} = 2 \times I_{GT} P_{W} = 15 \mu s I_{T} = 16 A$	_	1	_	μs
V_{GRM}	Peak Reverse Gate Voltage	I _{GR} = 10 μA	6	_	_	V

Static Characteristics

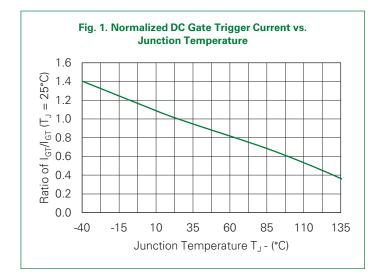
Symbol	Characteristic	Conditions		Value			Unit
Зуппоп	Gilaracteristic		Min.	Тур.	Max.	Oilit	
V_{TM}	Peak On-state Voltage Drop	$I_T = 16A; t_p = 380 \mu s$			-	1.6	V
	Popositivo Pook Off state Current	V -V -600V	T _J = 25°C	-	-	5	μΑ
I _{DRM}	Repetitive Peak Off-state Current	$V_D = V_{DRM} = 600 \text{ V}$ $T_J = 150^{\circ}\text{C}; \text{ RGK} = 220 \Omega$		-	-	2	mA

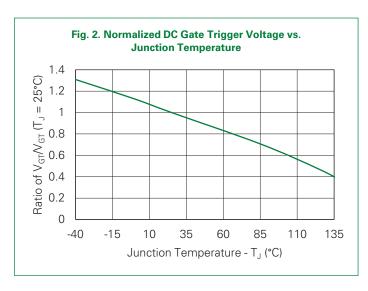
Thermal Resistances

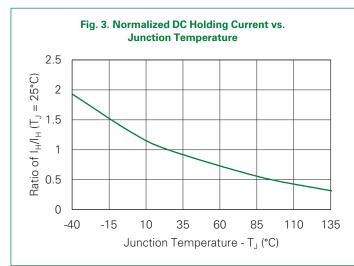
Symbol	Characteristic	Conditions	Value	Unit
$R_{\theta(JC)}$	Thermal Resistance, Junction to case (AC)	_	1.2	°C/W

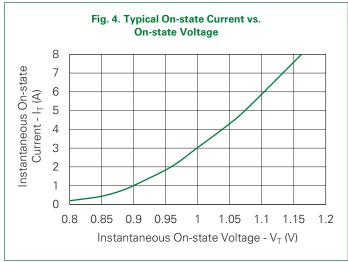


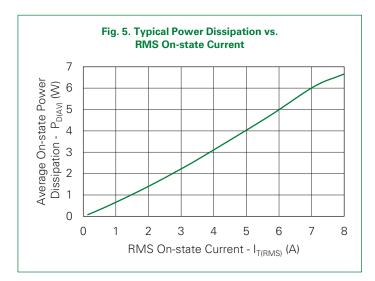
Characteristic Curves

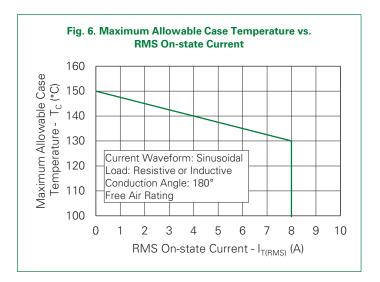


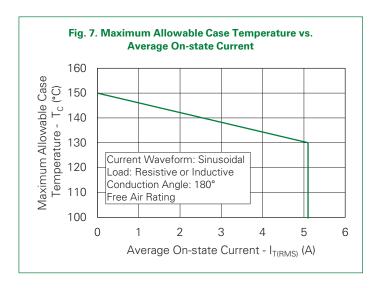


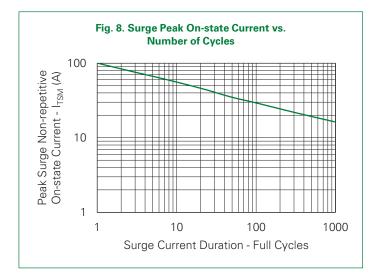












SUPPLY FREQUENCY: 60 Hz Sinusoidal LOAD: Resistive
RMS On-State Current: [[see, sel]: Maximum R

RMS On-State Current: $[I_{T(RMS)}]$: Maximum Rated Value at Specified Case Temperature

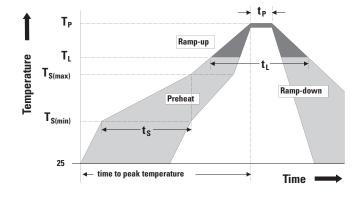
Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.



Soldering Parameters

	Characteristic	Value	
Reflow Co	ondition	Pb – Free assembly	
	Temperature Min (T _{s(min)})	150°C	
Pre-heat	Temperature Max (T _{s(max)})	200°C	
	Time (min to max) (t _s)	60 – 120 secs	
Average r	amp up rate (Liquidus Temp)(T _L) to peak	3°C/second max	
T _{S(max)} to T	L - Ramp-up Rate	3°C/second max	
Reflow	Temperature (T _L) (Liquidus)	217°C	
nellow	Time (t _L)	60 – 150 seconds	
Peak Tem	oerature (T _P)	260 ^{+0/-5} °C	
Time with	in 5°C of actual peak Temperature (t _p)	30 seconds max	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes max	
Do Not Ex	ceed	260°C	



Physical Specifications

Characteristic	Value
Terminal Finish	100% Matte Tin-plated
Body Material	UL Recognized compound meeting flammability rating V-0
Lead Material	Copper Alloy

Design Considerations

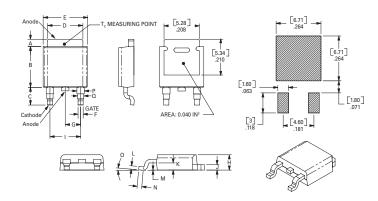
Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage for 1008 hours
Temperature/Humidity	EIA / JEDEC, JESD22-A101, 1008 hours; 160V - DC: 85°C; 85% relative humidity
Temperature Cycling	MIL-STD-750, M-1051, 1000 cycles; -55°C to +150°C; 15-min dwell-time
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Moisture Sensitivity Level	Level 1



Part Outline Drawing (TO-252AA) (D Package) – DPAK Surface Mount)



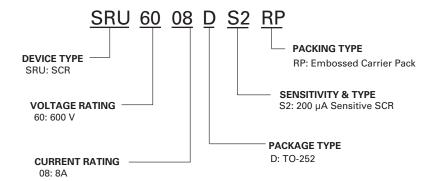
Cumbal	Inches			Millimeters			
Symbol	Min.	Typical	Max.	Min.	Typical	Max	
A	0.037	0.040	0.043	0.94	1.01	1.09	
В	0.235	0.243	0.245	5.97	6.16	6.22	
С	0.106	0.108	0.113	2.69	2.74	2.87	
D	0.205	0.208	0.213	5.21	5.29	5.41	
Е	0.255	0.262	0.265	6.48	6.65	6.73	
F	0.027	0.031	0.033	0.69	0.80	0.84	
G	0.087	0.090	0.093	2.21	2.28	2.36	
Н	0.085	0.092	0.095	2.16	2.33	2.41	
I	0.176	0.179	0.184	4.47	4.55	4.67	
J	0.018	0.020	0.023	0.46	0.51	0.58	
K	0.035	0.037	0.039	0.90	0.95	1.00	
L	0.018	0.020	0.023	0.46	0.51	0.58	
М	0.000	0.000	0.004	0.00	0.00	0.10	
N	0.021	0.026	0.027	0.53	0.67	0.69	
0	0°	0°	5°	0°	0°	5°	
Р	0.042	0.047	0.052	1.06	1.20	1.32	
Q	0.034	0.039	0.044	0.86	1.00	1.11	

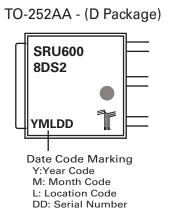
Packing Options

Part Number	Marking	Package	Туре	Weight	Packing Mode	Base Quantity
SRU6008DS2RP	SRU6008DS2	TO-252	Sensitive SCR	0.3 g	Embossed Carrier	2500



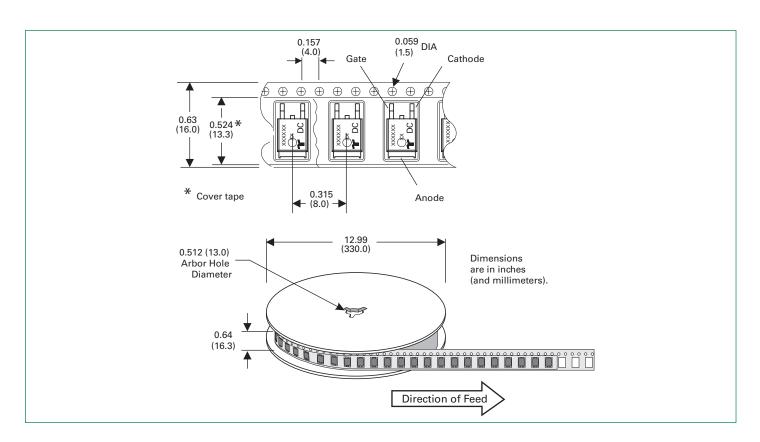
Part Numbering and Marking





TO-252 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-418-2 Standards



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